

# Dual Output 150/300-mA Low Dropout Regulator

### DESCRIPTION

SiP2211 is a dual output low dropout regulator capable of supplying 150 mA from output 1 and 300 mA from output 2. The SiP2211 has the outputs independently enabled. Also the SiP2211 offers a low dropout, low ground current and extremely low noise with the addition of a bypass capacitor.

Protection features include undervoltage lockout, output current limit, and thermal shutdown.

The Fixed output version of SiP2211 is available in a lead (Pb)-free MLP33-10 PowerPAK package and the adjustable version is available in a lead (Pb)-free MLP44-16 PowerPak package. Both packages ares specified to operate over the range of - 40  $^{\circ}$ C to 85  $^{\circ}$ C.

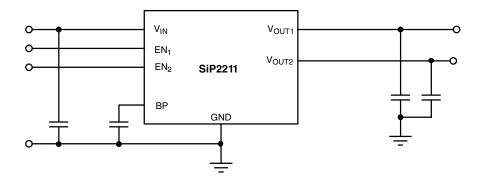
### **FEATURES**

- 2.25 V to 5.5 V Input Voltage Range
- Two Outputs 150 mA and 300 mA
- Low Ground Current of 48 μA
- Low Dropout Voltage of 65 mV at 100 mA
- Current Limit
- Thermal Shutdown
- MLP33-10 PowerPAK<sup>®</sup> Package (Fixed Output)
- MIC2211 Pin for Pin Replacement

#### **APPLICATIONS**

- Cellular Phones
- Wireless Modems
- PDAs

#### **TYPICAL APPLICATION CIRCUIT**





COMPLIANT



| ABSOLUTE MAXIMUM RATINGS                   |                                |             |       |  |
|--|--------------------------------|-------------|-------|--|
| Parameter                                  |                                | Limit       | Unit  |  |
| V <sub>IN</sub> , V <sub>EN</sub> , to GND |                                | - 0.3 to 7  | V     |  |
| Power Dissipation                          | MLP33-10 PowerPAK <sup>b</sup> | 1600        | mW    |  |
|  | MLP44-16 PowerPAK <sup>c</sup> | 1880        | IIIVV |  |
| Storage Temperature                        |                                | - 55 to 150 | °C    |  |
| Thermal Resistance (MLP10 PowerPAK)        |                                | 50          | °C/W  |  |

Notes:

a. Device Mounted with all leads soldered or welded to PC board.

b. Derate 20 mW/°C above 70 °C.

c. Derate 23.5 mW/°C above 70 °C.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

| RECOMMENDED OPERATING RANGE                |             |      |  |  |
|--|-------------|------|--|--|
| Parameter                                  | Limit       | Unit |  |  |
| Input Voltage Range                        | 2.25 to 5.5 | V    |  |  |
| Enable Voltage Range                       | 0 to 5.5    | v    |  |  |
| Operating Temperature Range T <sub>A</sub> | - 40 to 85  | - °C |  |  |
| Operating Temperature Range T <sub>J</sub> | - 40 to 125 | C    |  |  |

| SPECIFICATIONS                            |                   |   |   |                  |                  |                  |        |  |
|---|-------------------|---|---|------------------|------------------|------------------|--------|--|
|   |                   | Test Conditions Unless Specified  | Limits  |                  |                  |                  |        |  |
| Parameter                                 | Symbol            | $V_{IN} = V_{OUT} + 1 V^{e}, C_{OUT} 1 \mu F, I_{OUT} = 100 \mu A,$<br>$T_{A} = 25 \ ^{\circ}C$ | Temp <sup>a</sup>                                       | Min <sup>b</sup> | Тур <sup>с</sup> | Max <sup>b</sup> | Unit   |  |
| Regulators                                |                   |   |   |                  |                  |                  |        |  |
| Output Voltage Accuracy                   |                   | From Nominal V <sub>OUT</sub>   | Room  | - 1              |                  | 1                | %      |  |
| Output Voltage Acculacy                   |                   |   | Full  | - 2              |                  | 2                | 70     |  |
| Output Voltage<br>Temperature Coefficient |                   |   | Room  |                  | 40               |                  | ppm/°C |  |
| Line Degulation <sup>e</sup>              |                   | V <sub>IN</sub> = V <sub>OUT</sub> + 1 V to 5.5 V   | Room  | - 0.3            | 0.2              | 0.3              |        |  |
| Line Regulation <sup>e</sup>              |                   | $v_{\rm IN} = v_{\rm OUI} + 1 v_{\rm IO} 0.0 v$   | Full  | - 0.6            |                  | 0.6              | %      |  |
| Lood Regulation                           |                   | I <sub>OUT</sub> = 100 μA to 150 mA (LDO 1 and 2)   | Room  |                  | 0.2              | 1.0              | /0     |  |
| Load Regulation                           |                   | I <sub>OUT</sub> = 100 μA to 300 mA (LDO 2)   | Room  |                  |                  | 1.5              | 1      |  |
|   |                   | I <sub>OUT</sub> = 150 mA (LDO 1 and 2)   | Room  |                  | 120              | 190              | - mV   |  |
| Dropout Voltage <sup>f</sup>              | V                 |   | Full  |                  |                  | 250              |        |  |
|   | V <sub>DROP</sub> | I <sub>OUT</sub> = 300 mA (LDO 2)   | Room  |                  | 240              | 340              |        |  |
|   |                   |   | Full  |                  |                  | 420              |        |  |
|   |                   | I <sub>OUT1</sub> = I <sub>OUT2</sub> = 0 μA  | Room  |                  | 48               | 65               |        |  |
| Ground Pin Current                        | 1.                | $I_{OUT1} = I_{OUT2} = 0 \ \mu A$   | Full  |                  |                  | 80               | μΑ     |  |
| Ground Pin Current                        | l <sub>G</sub>    | I <sub>OUT1</sub> = 150 mA, I <sub>OUT2</sub> = 300 mA  | Room  |                  | 60               |                  |        |  |
|   |                   | V <sub>EN</sub> < 0.4 V   | Full  |                  |                  | 2.0              | 1      |  |
| Sequence Time Delay <sup>d</sup>          | t <sub>SEQ</sub>  |   | Room  |                  | 70               |                  | μs     |  |
| Output Voltage Noise                      |                   | C <sub>BP</sub> = 0.01 μF   |   |                  | 30               |                  | μVrms  |  |
| Ripple Rejection                          |                   | f = 1 kHz, $C_{OUT}$ = 1 $\mu$ F, $C_{BP}$ = 10 nF  | $_{JT} = 1 \ \mu\text{F}, C_{BP} = 10 \ \text{nF}$ Room |                  | 60               |                  | dB     |  |
|   |                   | f = 20 kHz, $C_{OUT}$ = 1 µF, $C_{BP}$ = 10 nF  | Room  |                  | 40               |                  | uВ     |  |
| Inputs                                    |                   |   |   |                  |                  |                  |        |  |
| EN Input Voltage                          | V <sub>IL</sub>   | Logic Low   | Full  |                  |                  | 0.6              | v      |  |
|   | V <sub>IH</sub>   | Logic High  | Full  | 1.8              |                  |                  | v      |  |
| EN Input Current                          | IIL               | V <sub>IL</sub> < 0.6 V   | Room  | - 1              | 0.01             | 1                | μA     |  |
|   | I <sub>IH</sub>   | V <sub>IH</sub> > 1.8 V   | Room  | - 1              | 0.01             | 1                | μη     |  |



## SPECIFICATIONS

| SPECIFICATIONS               |        |   |                   |                  |                  |                  |      |
|------------------------------|--------|---|-------------------|------------------|------------------|------------------|------|
|                              |        | Test Conditions Unless Specified                                    |                   | Limits           |                  |                  |      |
|                              |        | $V_{IN} = V_{OUT} + 1 V^{e}, C_{OUT} 1 \mu F, I_{OUT} = 100 \mu A,$ |                   |                  |                  |                  |      |
| Parameter                    | Symbol | $T_A = 25 \ ^{\circ}C$  | Temp <sup>a</sup> | Min <sup>b</sup> | Тур <sup>с</sup> | Max <sup>b</sup> | Unit |
| Protection                   |        |   |                   |                  |                  |                  |      |
| Current Limit                | IIL    | V <sub>OUT1</sub> = 0 V   | Room              | 150              | 280              | 460              | mA   |
|                              |        | V <sub>OUT1</sub> = 0 V   | Room              | 300              | 450              | 700              |      |
| Thermal Shutdown Temperature |        |   | Room              |                  | 165              |                  | °C   |
| Thermal Hysteresis           |        |   | Room              |                  | 25               |                  | C    |

Notes:

a. Room = 25 °C, Full = - 40 to 85 °C.

b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum.

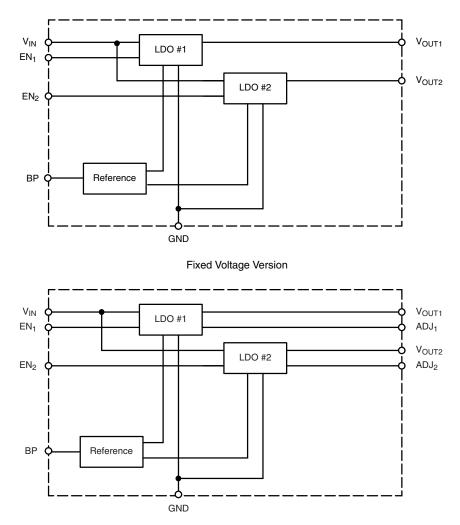
c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.

d. Timing is measured from 90 % of LDO #1's final value to 90 % of LDO #2's final value.

e. For higher output of the regulator pair.

f. Dropout voltage is defined as the input to output differential voltage at which the output voltage drops 2 % below the output voltage measured with a 1 V differential, provided that V<sub>IN</sub> does not drop below 2.25 V. When V<sub>OUT(nom)</sub> is less than 2.25 V, the output will be in regulation when 2.25 V - V<sub>OUT(nom)</sub> is greater than the dropout voltage specified.

### **FUNCTIONAL BLOCK DIAGRAM**



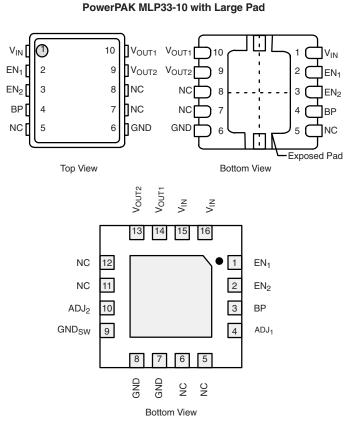
Adjustable Voltage Version

# SiP2211

# Vishay Siliconix



# PIN CONFIGURATION AND ORDERING INFORMATION



| VOLTAGE OPTIONS |             |  |  |  |
|-----------------|-------------|--|--|--|
| Voltage         | Code (x, Z) |  |  |  |
| Adj             | A           |  |  |  |
| 1.5             | F           |  |  |  |
| 1.6             | W           |  |  |  |
| 1.8             | G           |  |  |  |
| 1.85            | D           |  |  |  |
| 1.9             | Y           |  |  |  |
| 2.0             | Н           |  |  |  |
| 2.1             | E           |  |  |  |
| 2.5             | J           |  |  |  |
| 2.6             | К           |  |  |  |
| 2.7             | L           |  |  |  |
| 2.8             | М           |  |  |  |
| 2.85            | Ν           |  |  |  |
| 2.9             | 0           |  |  |  |
| 3.0             | Р           |  |  |  |
| 3.1             | Q           |  |  |  |
| 3.2             | R           |  |  |  |
| 3.3             | S           |  |  |  |
| 3.4             | Т           |  |  |  |
| 3.5             | U           |  |  |  |
| 3.6             | V           |  |  |  |

| ORDERING INFORMATION |               |                   |         |  |
|----------------------|---------------|-------------------|---------|--|
| Part Number          | Temp Range    | Package           | Marking |  |
| SiP2211DMP-XZ-E3     | - 40 to 85 °C | PowerPAK MLP33-10 | 11XZ    |  |
| SiP2211DLP-AA-E3     | - 40 10 65 °C | PowerPAK MLP44-16 | 11AA    |  |

X: Output 1 voltage code

Z: Output 2 voltage code

| PIN DESCRIPTION |          |                   |  |  |  |
|-----------------|----------|-------------------|--|--|--|
| Pin Nu          | umber    | Name              | Function   |  |  |
| MLP33-10        | MLP44-16 | Name              | Function   |  |  |
| 1               | 15, 16   | V <sub>IN</sub>   | Input voltage for the power MOSFETs and their gate drive |  |  |
| 2               | 1        | EN <sub>1</sub>   | Enables LDO #1 output                                    |  |  |
|                 | 6        | NC                | No Connection  |  |  |
| 3               | 2        | EN <sub>2</sub>   | Enables LDO #2 output                                    |  |  |
| 4               | 3        | BP                | Bypass for noise reduction                               |  |  |
|                 | 4        | ADJ <sub>1</sub>  | Feedback connection for LDO #1                           |  |  |
| 5               | 5        | NC                | No Connection  |  |  |
| 6               | 7, 8     | GND               | Ground   |  |  |
|                 | 9        | GND <sub>SW</sub> | Ground for the internal N-Channel MOSFET switch          |  |  |
|                 | 10       | ADJ <sub>2</sub>  | Feedback connection for LDO #2                           |  |  |
| 7               | 11       | NC                | No Connection  |  |  |
| 8               | 12       | NC                | No Connection  |  |  |
| 9               | 13       | V <sub>OUT2</sub> | Output of LDO #2 - 300 mA                                |  |  |
| 10              | 14       | V <sub>OUT1</sub> | Output of LDO #1 - 150 mA                                |  |  |

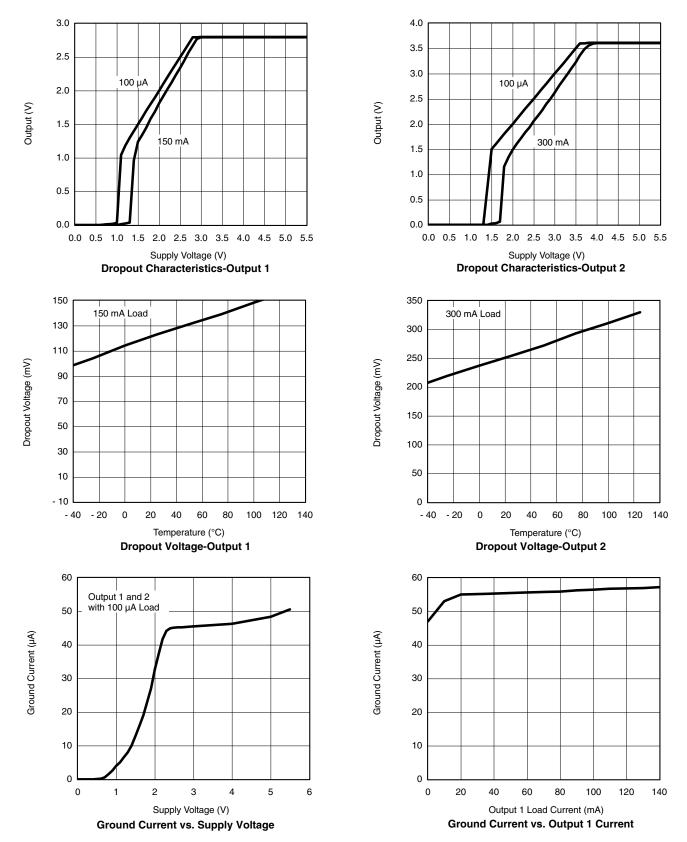
The exposed pad on both packages must be connected externally to the GND pin.





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## **TYPICAL CHARACTERISTICS**



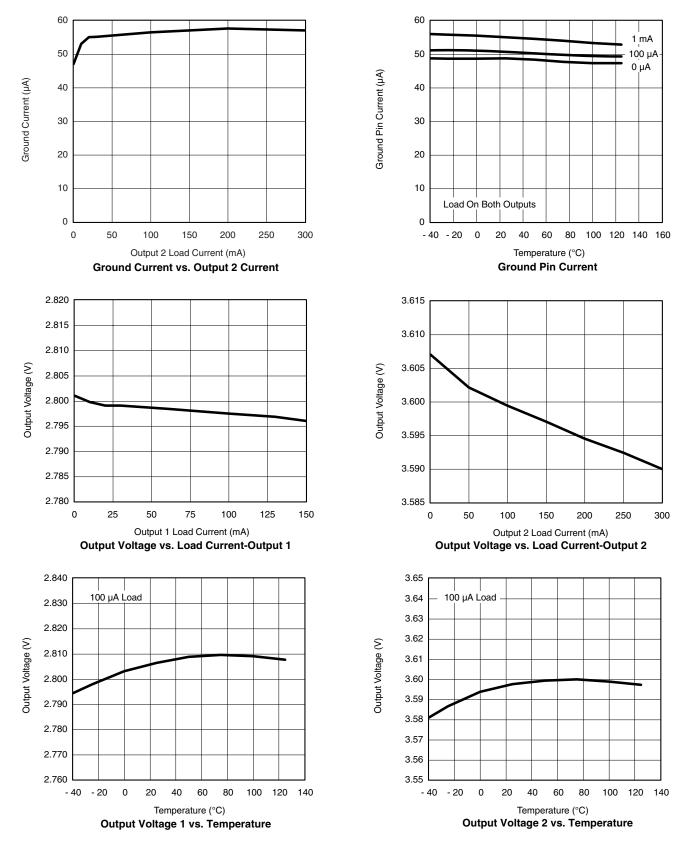
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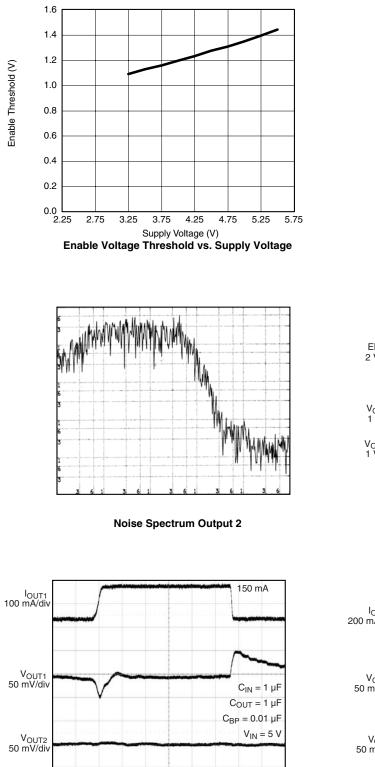
# **TYPICAL CHARACTERISTICS**





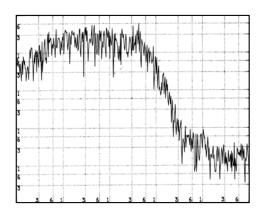
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## **TYPICAL CHARACTERISTICS**

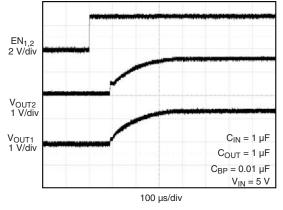


Load Transient Response LDO #1

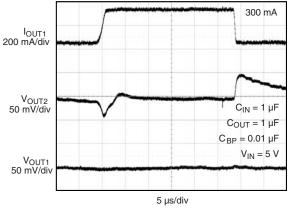
5 µs/div



Noise Spectrum Output 1



**Enable Sequence** 



Load Transient Response LDO #2

## **DETAILED OPERATION**

The SiP2211 is a low drop out, low quiescent current monolithic dual linear regulator, with power-on reset and open drain driver output features. With output voltage range from 1.25 V to 5 V the first regulator can source 150 mA and the second regulator can source 300 mA. The open drain driver has the capability to drive LED's for backlighting applications.

### V<sub>IN</sub>

 $V_{\rm IN}$  is the input supply pin for both LDO's. The bypass capacitor for this pin is not critical as long as the input supply has low enough source impedance. For practical circuits, a 1.0  $\mu F$  or larger ceramic capacitor is recommended. When the source impedance is not low enough and/or the source is several inches from the SiP2211, then a larger input bypass capacitor is needed. When the source impedance, wire and trace impedance are unknown, it is recommended that an input bypass capacitor be used of a value that is equal to or greater than the output capacitor.



### V<sub>OUT1,2</sub> (LDO Outputs)

The V<sub>OUT</sub> is the output voltage of the regulator. Connect a bypass capacitor from V<sub>OUTx</sub> to ground. The output capacitor can be any value from 1.0  $\mu$ F to 10.0  $\mu$ F. A ceramic capacitor with X5R or X7R dielectric type is recommended for best output noise, line transient, and load transient performance.

#### Enable

The EN1 and EN2 pins control the turning on and off of their respective regulators in the SiP2211.  $V_{OUT}$  of both outputs are guaranteed to be on when the Enable pin voltage is equal or greater than 1.8 V.  $V_{OUT}$  is guaranteed to be off when the Enable pin voltage equals or is less than 0.6 V. To automatically turn on  $V_{OUT}$  whenever the Input is applied, tie the Enable pin to  $V_{IN}$ .

### **Bypass Capacitor**

For low noise application and/or increase in power supply rejection ration (PSRR) connect a high frequency ceramic capacitor from BP to ground. A 0.01  $\mu$ F X5R or X7R ceramic capacitor is recommended.

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